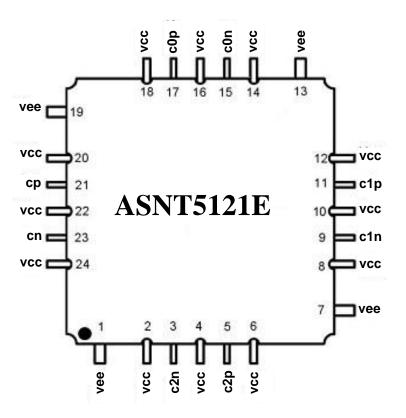


Ultra High-Speed Mixed Signal ASICs

Offices: 310-530-9400 / Fax: 310-530-9402 www.adsantec.com

ASNT5121E-KMC DC-64*Gbps* Data Distributor 1-to-3

- High-speed broadband Data Amplifier and Distributor
- Exhibits low jitter and limited temperature variation over industrial temperature range
- One input differential signal port and three differential amplified output signal ports
- Matched phase delays for all outputs
- Fully differential CML input interfaces
- Fully differential CML output interface with 350mV single-ended swing
- Single +3.3V or -3.3V power supply
- Power consumption: 710*mW*
- Fabricated in SiGe for high performance, yield, and reliability
- Custom CQFP 24-pin package





DESCRIPTION

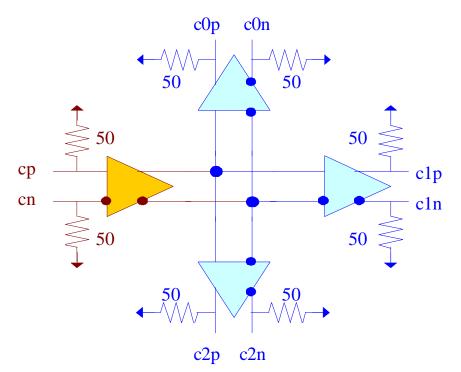


Fig. 1. Functional Block Diagram

The temperature stable ASNT5121E-KMC SiGe IC provides active broadband data signal splitting, and is intended for use in high-speed measurement / test equipment. The IC shown in Fig. 1 can process a broadband high-speed data input signal cp/cn and deliver three broadband high-speed data phase matched output signals c0p/c0n, c1p/c1n, c2p/c2n.

The part's I/O's support the CML logic interface with on chip 50*Ohm* termination to **vcc** and may be used differentially, AC/DC coupled, single-ended, or in any combination (see also POWER SUPPLY CONFIGURATION). In the DC-coupling mode, the input signal's common mode voltage should comply with the specifications shown in ELECTRICAL CHARACTERISTICS. In the AC-coupling mode, the input termination provides the required common mode voltage automatically. The differential DC signaling mode is recommended for optimal performance.

POWER SUPPLY CONFIGURATION

The part can operate with either a negative supply (vcc = 0.0V = ground and vee = -3.3V), or a positive supply (vcc = +3.3V and vee = 0.0V = ground). In case of a positive supply, all I/Os need AC termination when connected to any devices with 50*Ohm* termination to ground. Different PCB layouts will be needed for each different power supply combination.

All the characteristics detailed below assume vcc = 0.0V and vee = -3.3V.

Rev. 1.1.2



ABSOLUTE MAXIMUM RATINGS

Caution: Exceeding the absolute maximum ratings may cause damage to this product and/or lead to reduced reliability. Functional performance is specified over the recommended operating conditions for power supply and temperature only. AC and DC device characteristics at or beyond the absolute maximum ratings are not assumed or implied. All min and max voltage limits are referenced to ground (VCC).

Parameter	Min	Max	Units
Supply Voltage (vee)		-3.6	V
Power Consumption		0.77	W
RF Input Voltage Swing (SE)		1.0	V
Case Temperature		+90	°С
Storage Temperature	-40	+100	°С
Operational Humidity	10	98	%
Storage Humidity	10	98	%

TERMINAL FUNCTIONS

TERMINAL		AL	DESCRIPTION			
Name	No.	Туре				
	High-Speed I/Os					
ср	21	CML	Differential high speed data/clock inputs with internal SE 500hm			
cn	23	input	termination to VCC			
c0p	17	CML	Differential high speed data/clock outputs with internal SE 500hm			
c0n	15	output	termination to vcc. Require external SE 50 <i>Ohm</i> termination to vcc			
c1p	11	CML	Differential high speed data/clock outputs with internal SE 500hm			
c1n	9	output	termination to vcc. Require external SE 50 <i>Ohm</i> termination to vcc			
c2p	5	CML	Differential high speed data/clock outputs with internal SE 500hm			
c2n	3	output	termination to vcc. Require external SE 500hm termination to vcc			
	Supply and Termination Voltages					
Name Description			escription	Pin Number		
vcc	Positive power supply $(+3.3V \text{ or } 0)$			2, 4, 6, 8, 10, 12, 14, 16, 18, 20, 22, 24		
vee	ee Negative power supply $(0V \text{ or } -3.3V)$		er supply $(0V \text{ or } -3.3V)$	1, 7, 13, 19		



ELECTRICAL CHARACTERISTICS

PARAMETER	MIN	TYP	MAX	UNIT	COMMENTS	
General Parameters						
vee	-3.1	-3.3	-3.5	V	±6%	
VCC		0.0		V	External ground	
Ivee		215		mА		
Power consumption		710		mW		
Junction temperature	-40	25	125	°C		
HS Input Data (cp/cn)						
Data Rate	DC		64	Gbps		
Swing	0.05		1.0	V	Differential or SE, p-p	
CM Voltage Level	vcc-0.8	3	VCC	V	Must match for both inputs	
HS Output Data (c0p/c0n, c1p/c1n, c2p/c2n)						
Data RateDC64Gbps						
Logic "1" level		VCC		V		
Logic "0" level		vcc-0.35		V	With external 500hm DC termination	
Rise/Fall times	6	8	10	ps	20%-80%	
Output Jitter			1	ps	Peak-to-peak	
Duty cycle	45	50	55	%	For clock signal	

PACKAGE INFORMATION

The chip die is housed in a custom 24-pin CQFP package shown in Fig. 2. The package provides a center heat slug located on its back side to be used for heat dissipation. ADSANTEC recommends for this section to be soldered to the **vcc** plain, which is ground for a negative supply, or power for a positive supply.

The part's identification label is ASNT5121E-KMC. The first 9 characters of the name before the dash identify the bare die including general circuit family, fabrication technology, specific circuit type, and part version while the 3 characters after the dash represent the package's manufacturer, type, and pin out count.

This device complies with the Restriction of Hazardous Substances (RoHS) per 2011/65/EU for all ten substances.



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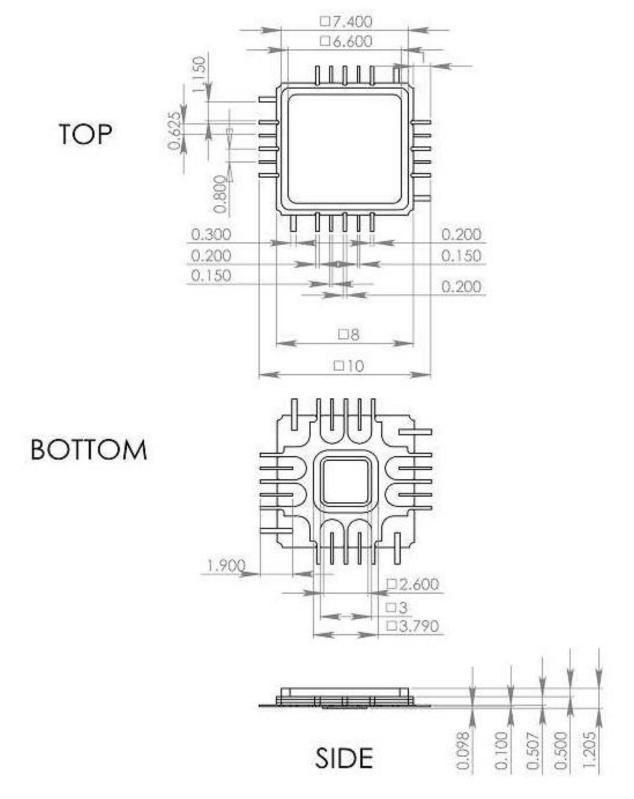


Fig. 2. CQFP 24-Pin Package Drawing (All Dimensions in mm)



REVISION HISTORY

Revision	Date	Changes	
1.1.2	05-2020	Updated Package Information	
1.0.2	07-2019	Updated Letterhead	
1.0.1	08-2015	First release	
1.0.0	09-2014	Preliminary release	